









CEF540L

100V A 40mΩ A 36ANote 4 A Si MOSFET

SILICON Si MOSFET ▲ THT type
N-channel enhancement mode
UL94V-0 rated flame retardant epoxy

TO220F-3L package ▲ Electrical insulated mounting tab

Super high dense cell density for extremely low R_{DS(ON)}

High power and current handling capability

MAXIMUM RATINGS

| Parameter (T _C = 25°C, unless otherwise noted) | | Characteristics |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage | V _{DS} | 100V |
| Gate-Source Voltage | V _{GS} | ±20V |
| Continuous Drain Current at T _C = 25°C | I _D | 36A Note 4 |
| Pulsed Drain Current Note 1 | I _{DM} Note 5 | 120A Note 4 |
| Maximum Power Dissipation at T _C = 25°C | P _D | 140W |
| Power Dissipation Derating above 25°C | ΔP _D | 0.91W/°C |
| Single Pulsed Avalanche Energy Note 6 | E _{AS} | 310mJ |
| Single Pulsed Avalanche Current Note 6 | I _{AS} | 18A |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55°C to +175°C |

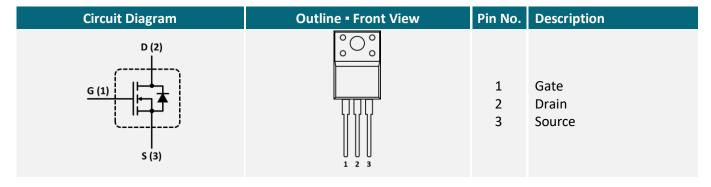
THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|---|--------------------|---------|
| Thermal Resistance, Junction-to-Case | R _{TH_JC} | 1.1°C/W |
| Thermal Resistance, Junction-to-Ambient | R _{TH_JA} | 65°C/W |

APPLICATIONS

| Battery Management Systems | E-Bike | Industrial Control | Power Inverter | UPS |
|----------------------------|--------|-----------------------|-------------------|-----|
| +4- | 50 | | | |

PIN DESCRIPTION





ELECTRICAL CHARACTERISTICS ▲ T_C = 25°C, unless otherwise noted

| Item | Condition | Symbol | Min. | Тур. | Max. | Unit |
|--|--|---------------------|------|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V$, $I_{D} = 250\mu A$ | BV_{DSS} | 100 | | | V |
| Zero Gate Voltage Drain Current | $V_{DS} = 100V, V_{GS} = 0V$ | I _{DSS} | | | 25 | μΑ |
| Gate Body Leakage Current, Forward | $V_{GS} = 20V, V_{DS} = 0V$ | I _{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | $V_{GS} = -20V, V_{DS} = 0V$ | I_{GSSR} | | | -100 | nA |
| On Characteristics Note 3 | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_{D} = 250 \mu A$ | $V_{GS(th)}$ | 1 | | 3 | V |
| Static Drain-Source On-Resistance | $V_{GS} = 10V, I_D = 18A$ | R _{DS(ON)} | | 40 | 50 | mΩ |
| Static Drain-Source On-Resistance | $V_{GS} = 5V$, $I_D = 15A$ | R _{DS(ON)} | | 43 | 53 | mΩ |
| Forward Transconductance | $V_{DS} = 25V, I_{D} = 18A$ | g _{FS} | | 14 | | S |
| Dynamic Characteristics Note 3 | | | | | | |
| Input Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C _{ISS} | | 1295 | | pF |
| Output Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | Coss | | 199 | | pF |
| Reverse Transfer Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C_{RSS} | | 40 | | pF |
| Switching Characteristics Note 3 | | | | | | |
| Turn-On Delay Time | V_{DD} = 50V, V_{GS} = 10V, I_{D} = 18A, $R_{G(ext)}$ = 5.1 Ω | t _{D(ON)} | | 13 | 26 | ns |
| Turn-On Rise Time | V_{DD} = 50V, V_{GS} = 10V, I_{D} = 18A, $R_{G(ext)}$ = 5.1 Ω | t_R | | 3.1 | 7 | ns |
| Turn-Off Delay Time | V_{DD} = 50V, V_{GS} = 10V, I_{D} = 18A, $R_{G(ext)}$ = 5.1 Ω | t _{D(OFF)} | | 55 | 110 | ns |
| Turn-Off Fall Time | V_{DD} = 50V, V_{GS} = 10V, I_D = 18A, $R_{G(ext)}$ = 5.1 Ω | t _F | | 5 | 10 | ns |
| Total Gate Charge | $V_{DD} = 80V$, $V_{GS} = 10V$, $I_D = 18A$ | Q_{G} | | 40 | 80 | nC |
| Gate Source Charge | $V_{DD} = 80V$, $V_{GS} = 10V$, $I_D = 18A$ | Q_{GS} | | 3.7 | | nC |
| Gate Drain Charge | $V_{DD} = 80V$, $V_{GS} = 10V$, $I_D = 18A$ | Q_{GD} | | 10 | | nC |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| Drain-Source Diode Forward Current | | Is | | | 36 | Α |
| Drain-Source Diode Forward Voltage Note 2 | $V_{GS} = 0V$, $I_S = 18A$ | V_{SD} | | | 1.3 | V |

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: Limited only by maximum temperature allowed.
- 5: Pulse width limited by safe operating area.
- 6: L = 1mH, I_{AS} = 15A, V_{DD} = 50V, R_{G} = 25Ω, Starting T_{J} = 25°C.



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE



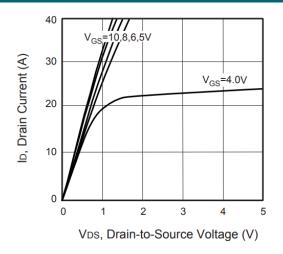


Fig. 2 • Transfer Characteristics

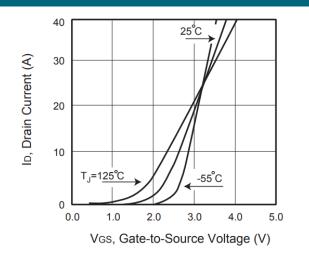


Fig. 3 • Capacitance

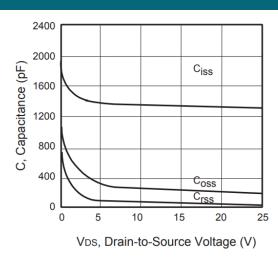


Fig. 4 • On-Resistance Variation with Temperature

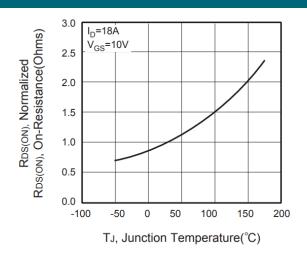


Fig. 5 • Gate Threshold Variation with Temperature

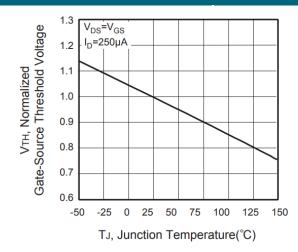
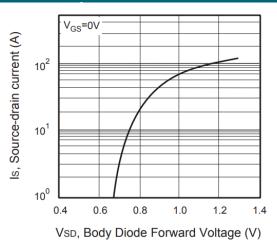


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



MGT ▲ Manufacturer Group of Technology



REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

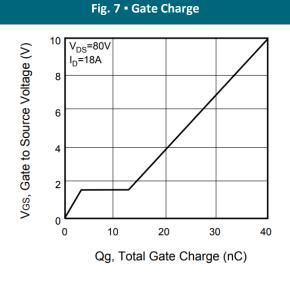


Fig. 8 • Maximum Safe Operating Area

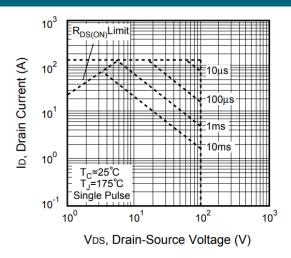
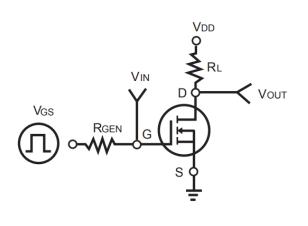


Fig. 9 • Switching Test Circuit

Fig. 10 • Switching Waveforms



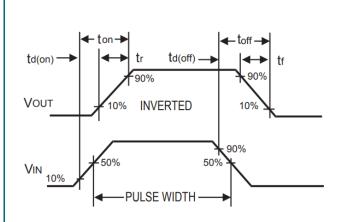
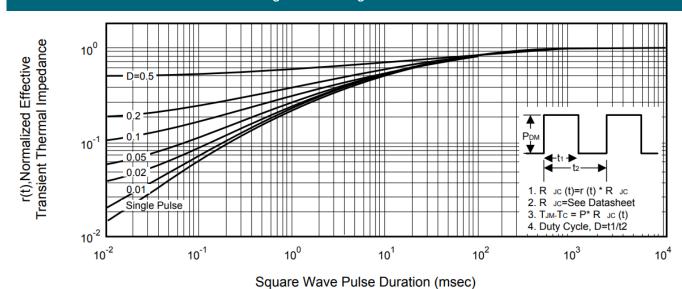


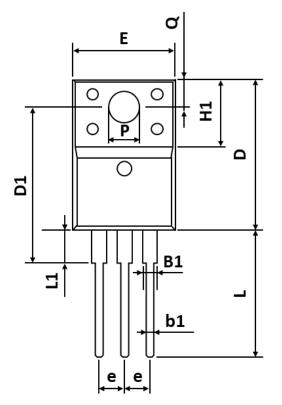
Fig. 11 • Switching Test Circuit

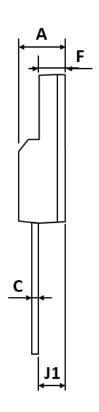


MGT ▲ Manufacturer Group of Technolog



PACKAGE OUTLINE





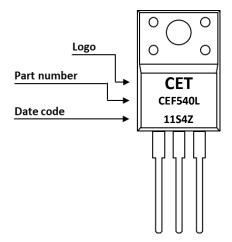
| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| Α | 4.500 | - | 5.000 |
| B1 | 1.000 | - | 1.500 |
| b1 | 0.700 | - | 0.950 |
| С | 0.420 | - | 0.700 |
| D | 15.670 | - | 16.070 |
| D1 | 14.800 | - | 16.000 |
| Е | 9.960 | - | 10.360 |
| е | 2.340 | - | 2.740 |
| F | 2.340 | - | 2.740 |
| H1 | 6.480 | - | 6.900 |
| J1 | 2.550 | - | 2.950 |
| L | 12.080 | - | 13.480 |
| L1 | 2.230 | - | 3.650 |
| Q | 3.100 | - | 3.500 |
| Р | 2.980 | - | 3.380 |

ORDERING INFORMATION

| Part Number | Package | Packing | Tube Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|------------|---------|-----------|----------------|----------------|
| CEF540L | TO-220F-3L | Tube | 50pcs | 1,000pcs | 4,000pcs |

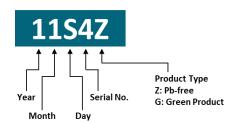


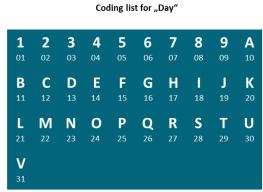
PART MARKING



DATE CODE

Example: 11S4Z

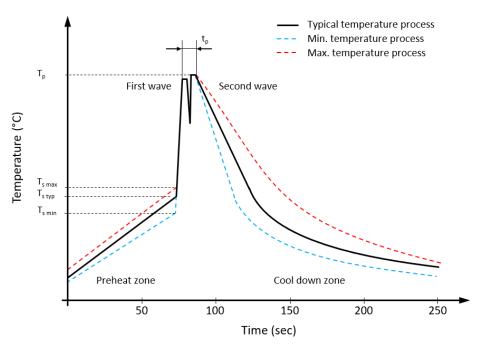








RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

| Profile Features | | Value ▲ Sn-Pb Assembly | Value ▲ Pb-free Assembly |
|--|--------------------|---|--|
| Preheat temperature min. | T_{smin} | 100 °C | 100 °C |
| Preheat temperature typical | T _{s typ} | 120 °C | 120 °C |
| Preheat temperature max. | T_{smax} | 130 °C | 130 °C |
| Preheat time t_s from T_{smin} to T_{smax} | ts | 70 seconds | 70 seconds |
| Peak temperature | T_p | 235 °C to 260 °C | 245 °C to 260 °C |
| Time of actual peak temperature | t _p | Max. 10 seconds Max. 5 second each wave | Max. 10 seconds Max. 5 second each wave |
| Ramp-down date min. | | ~ 2 °C/second | ~ 2 °C/second |
| Ramp-down rate typical | | ~ 3.5 °C/second | ~ 3.5 °C/second |
| Ramp-down rate max. | | ~ 5 °C/second | ~ 5 °C/second |
| Time 25°C to 25°C | | 4 minutes | 4 minutes |



REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
| | | | |
| | | | |
| | | | |
| | | | |
| | | | |

DISCLAIMER

Except for the written expressed warranties, MGT does not implicitly, by assumption or whatever else, warrant, under-take, promise any other warranty or guaranty for any MGT product.

All information and technical specifications made available by MGT are for guidance only and we reserve the right to change or modify them without prior notice. Unless expressly stated in writing by MGT, we reject any guarantees, obligations, or warranties.

All MGT products with the technical specifications described are suitable for use in certain applications. Operating, production, storage and environmental conditions can have a massive influence on the parameters mentioned in the data sheets, which cause the performance to vary over time.

It is subject to the user's duty of care to design and validate his products in such a way that appropriate measures are taken, such as protective circuits or redundant systems to ensure the safety standards required in the application.

MGT components are not designed or rated for use in life support, rescue, safety critical, military, or aerospace applications where failure or malfunction could result in property or environmental damage, serious injury or death. In the aforementioned cases, please contact us before using MGT products.

In principle, we reserve all rights and MGT's general terms and conditions apply. You can find them on our website www.mgt.co.com.